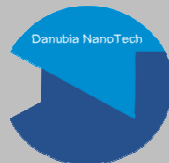


Ion-Irradiated Carbon Nanotube Networks: Correlated changes in Conduction and other properties

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Bratislava, Slovakia

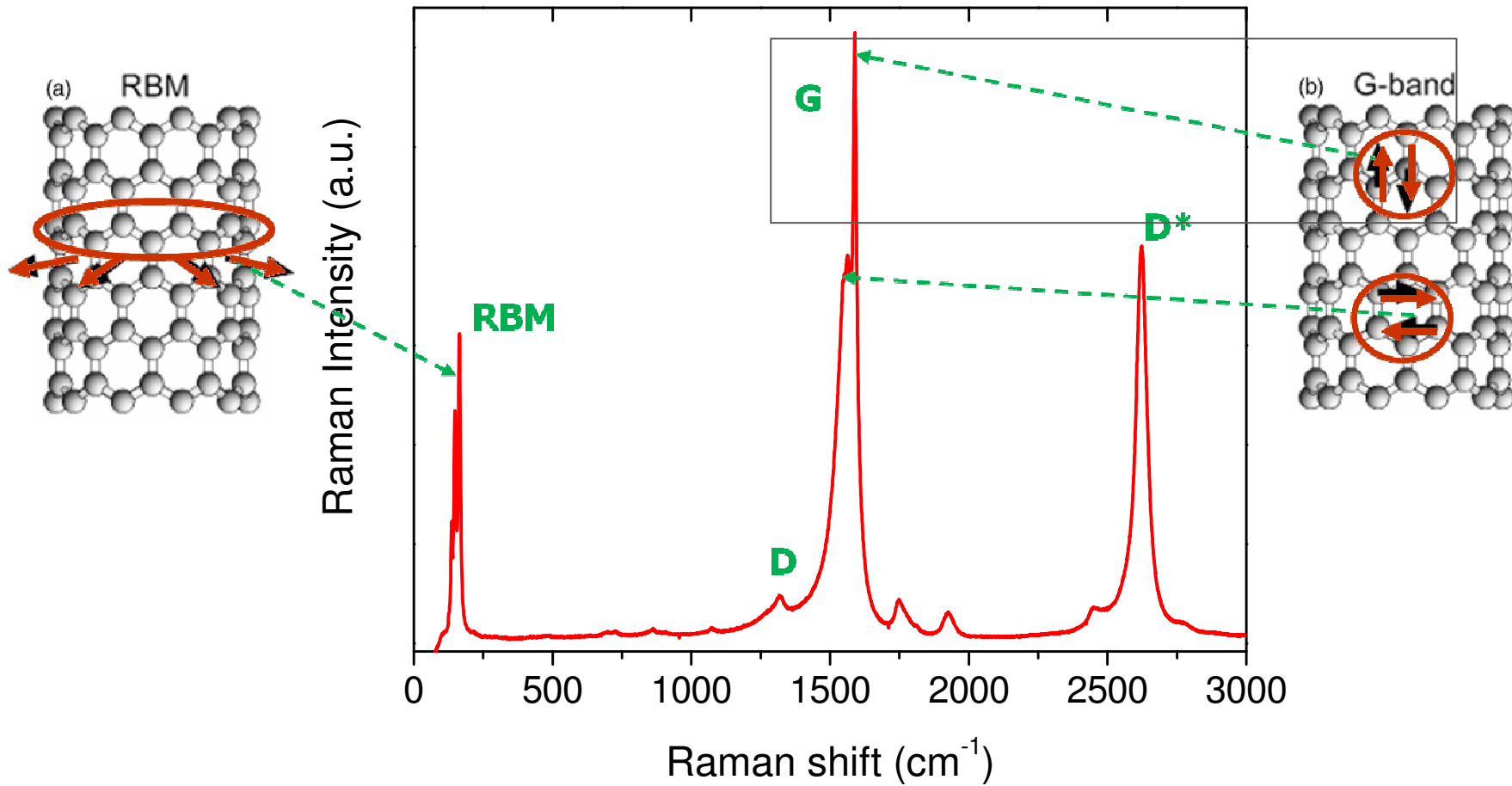
Characterization:

1. Raman spectroscopy
2. Optical spectroscopy (NIR,VIS)
3. Transmission electron microscopy (TEM, HRTEM)
4. Scanning electron microscopy (SEM)
5. Atomic force microscopy (AFM)

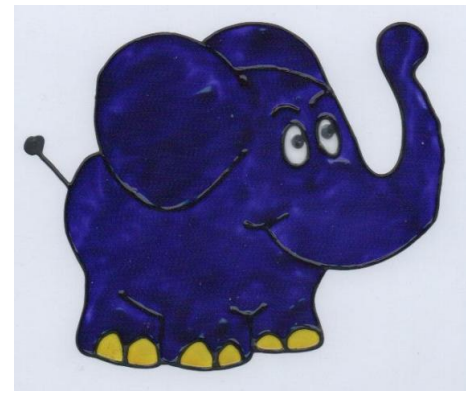
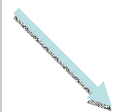
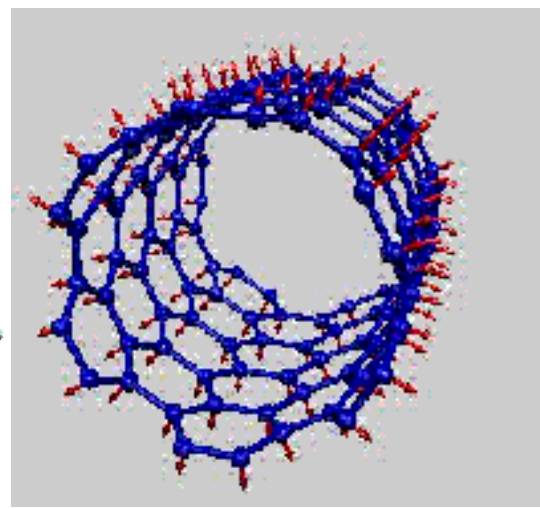
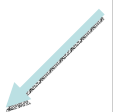
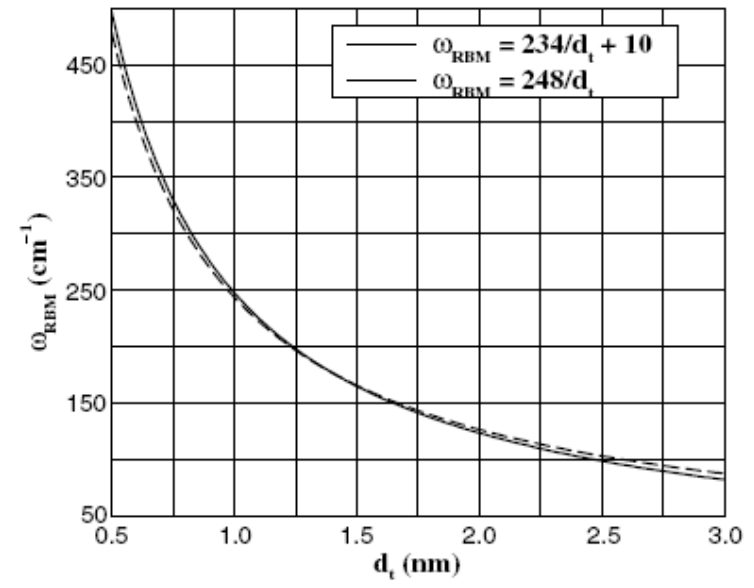


Raman spectroscopy

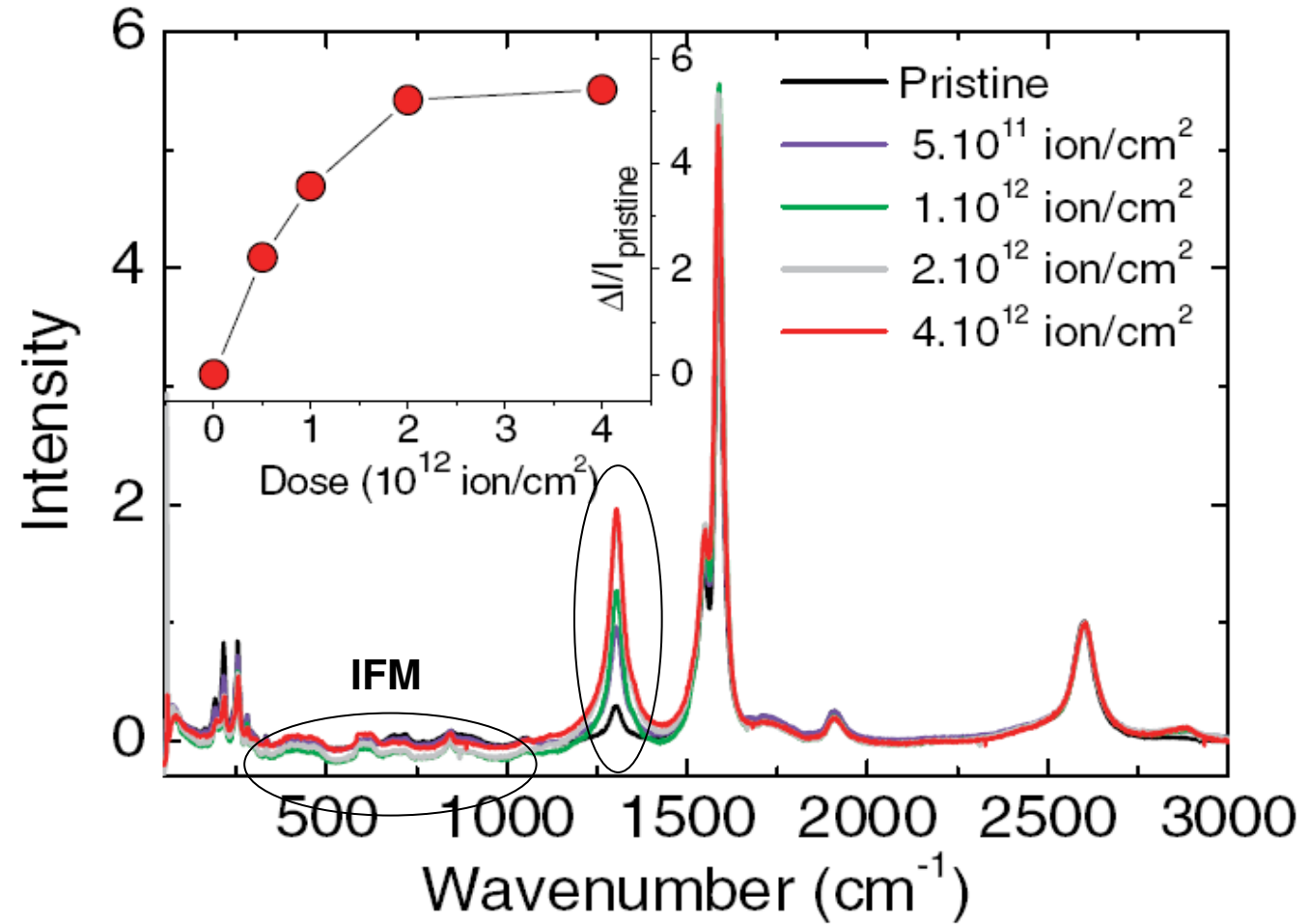
- inelastic photon scattering



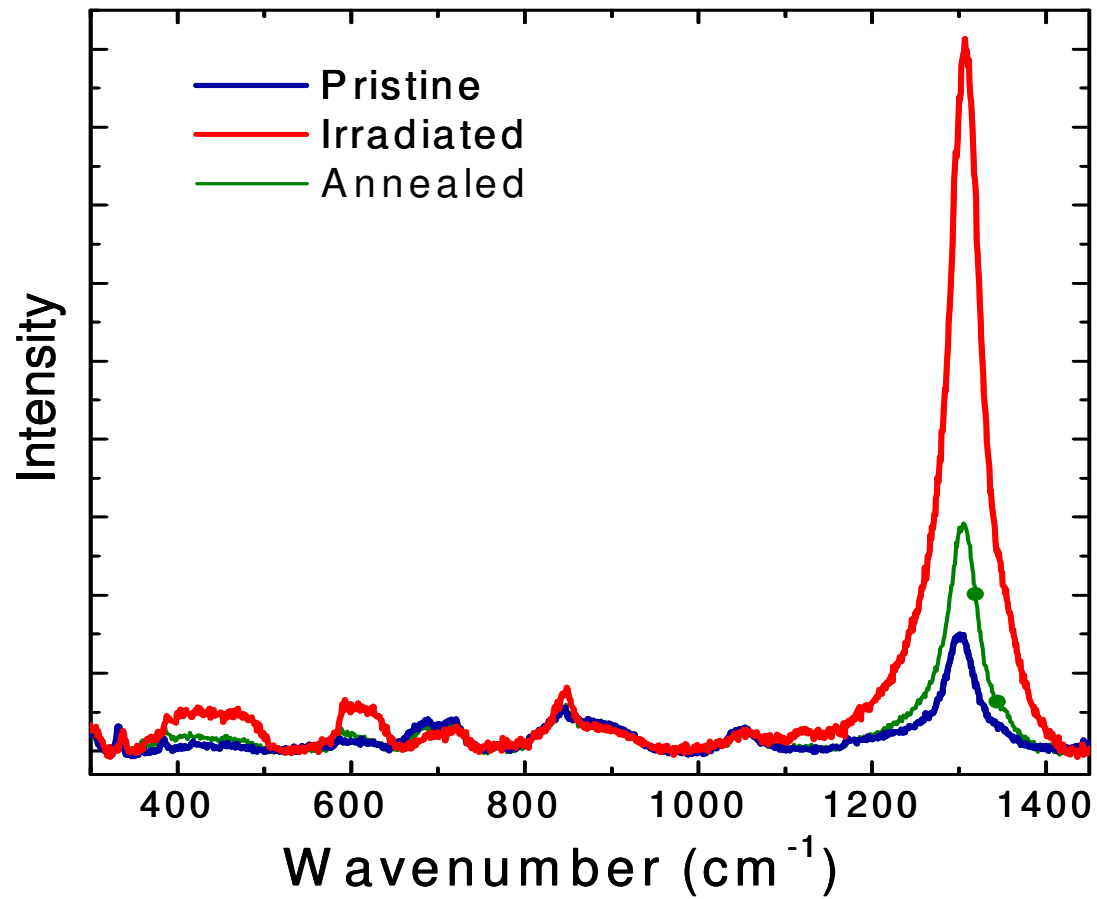
Radial Breathing Mode - RBM



Raman spectra of pristine and Ar⁺ irradiated SWNTs
Inset: $\Delta I/I$ of the D-mode vs. Dose of Ar⁺ ions

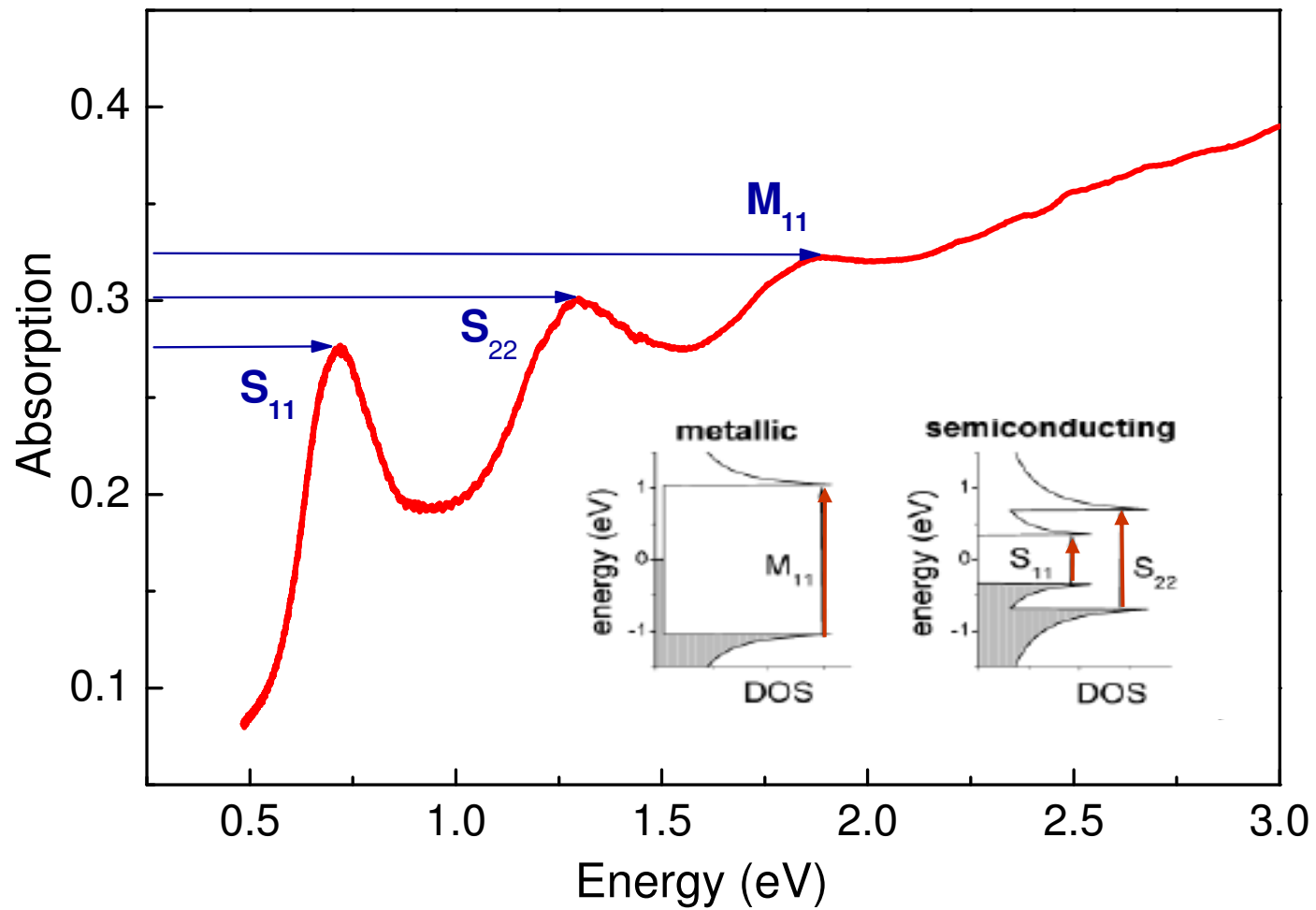


Effect of annealing

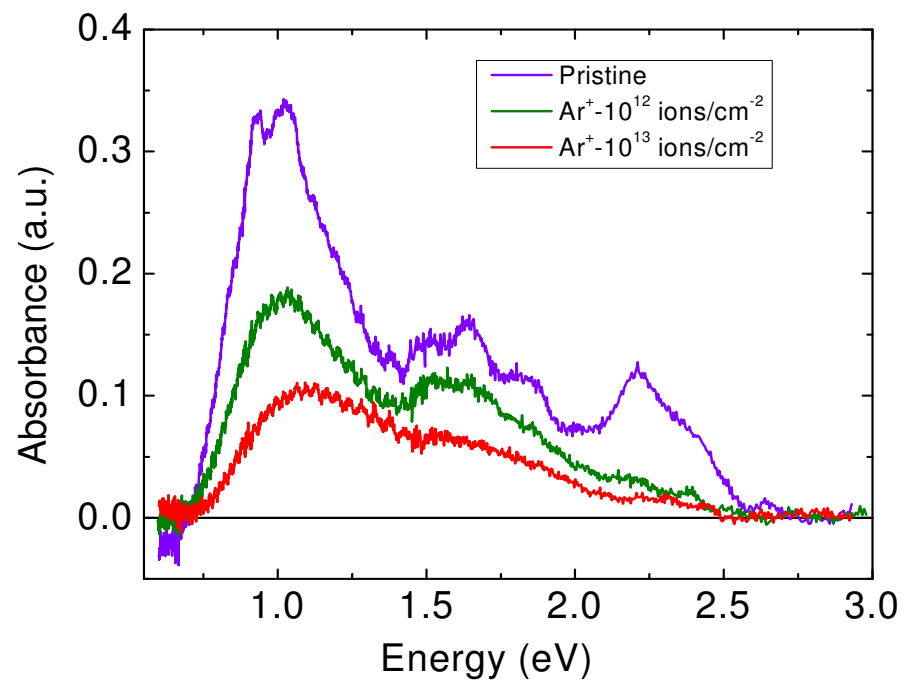
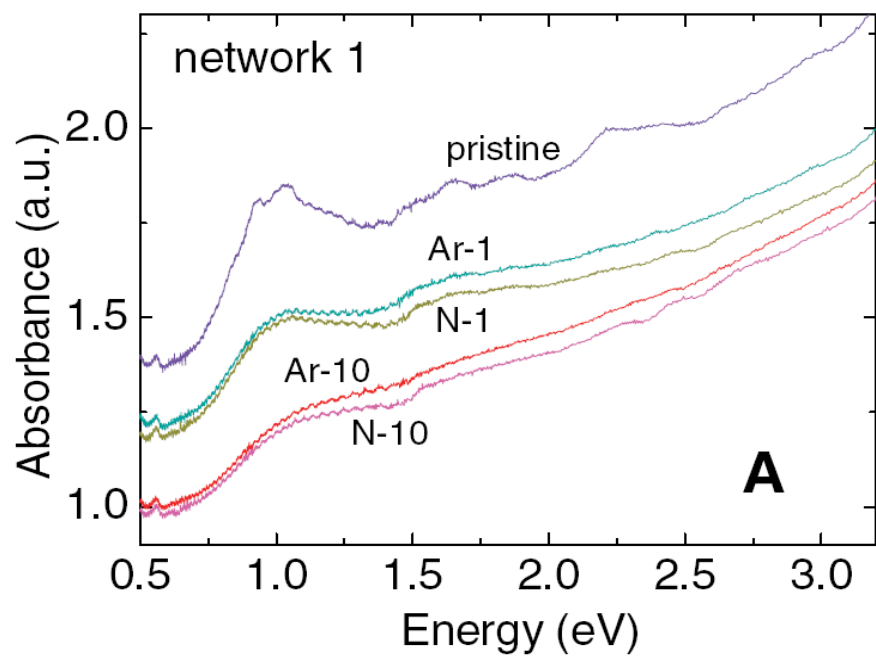


Viera Skákalová, Janina Maultzsch, Zoltán Osváth, László P. Biró, and Siegmur Roth,
Phys. Stat. Sol. (RRL) 1, No. 4, 138–140 (2007)

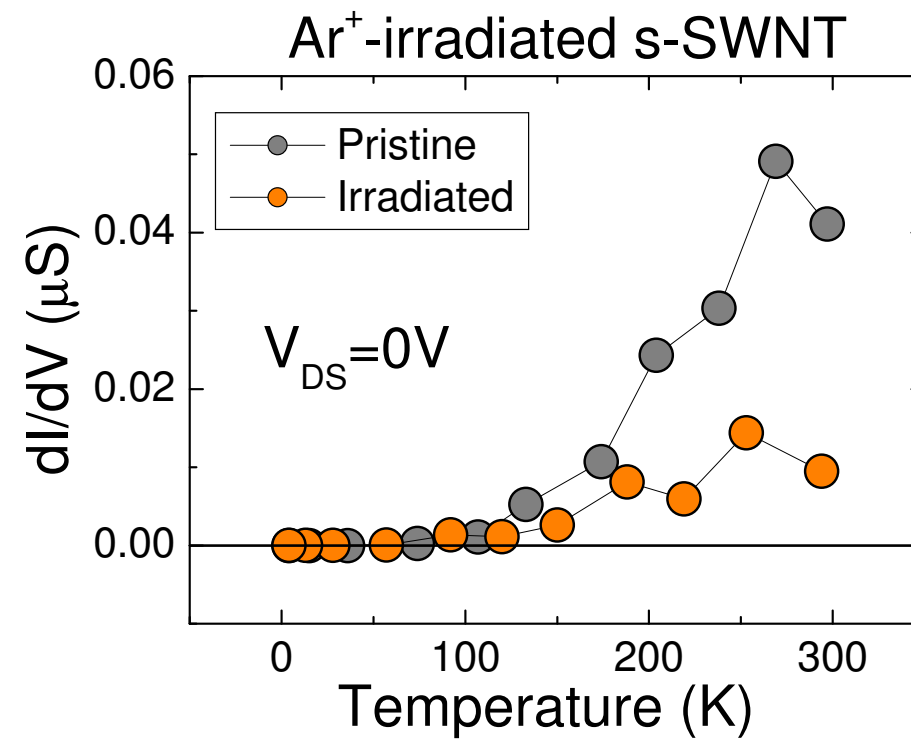
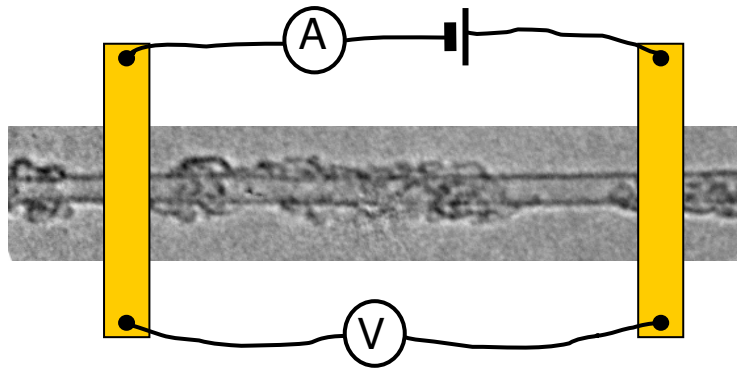
Optical spectroscopy



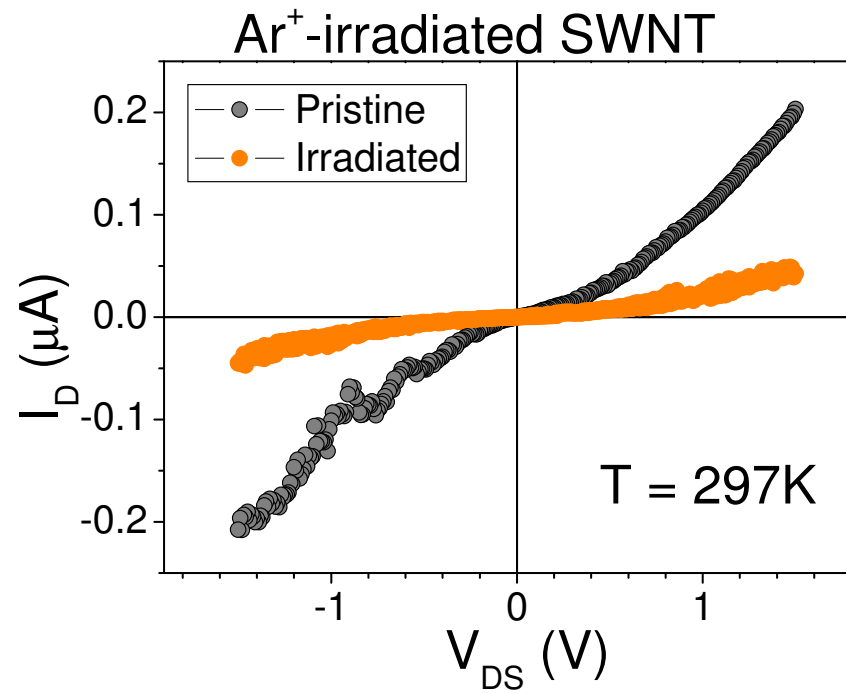
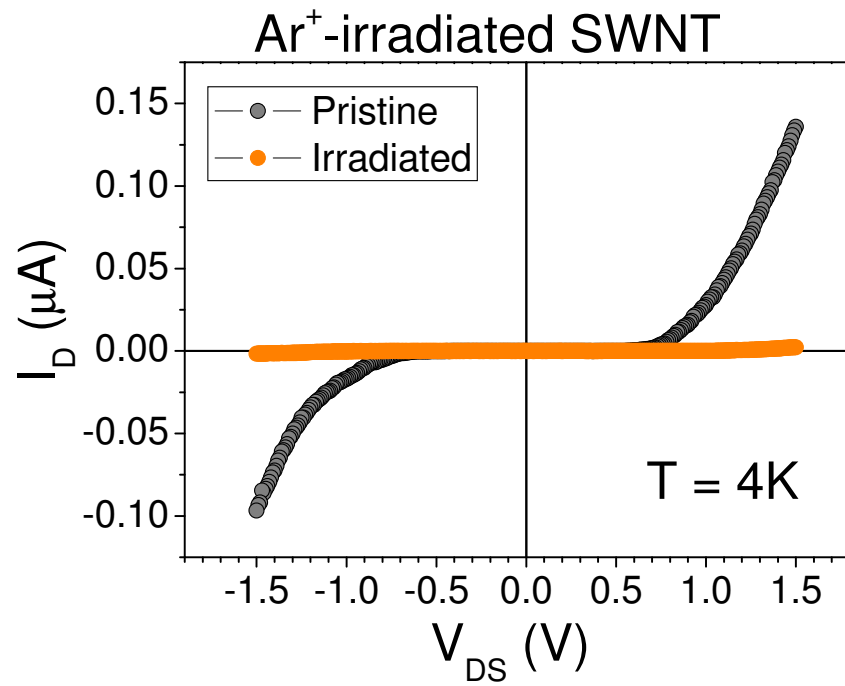
Optical absorption spectra of irradiated SWNT



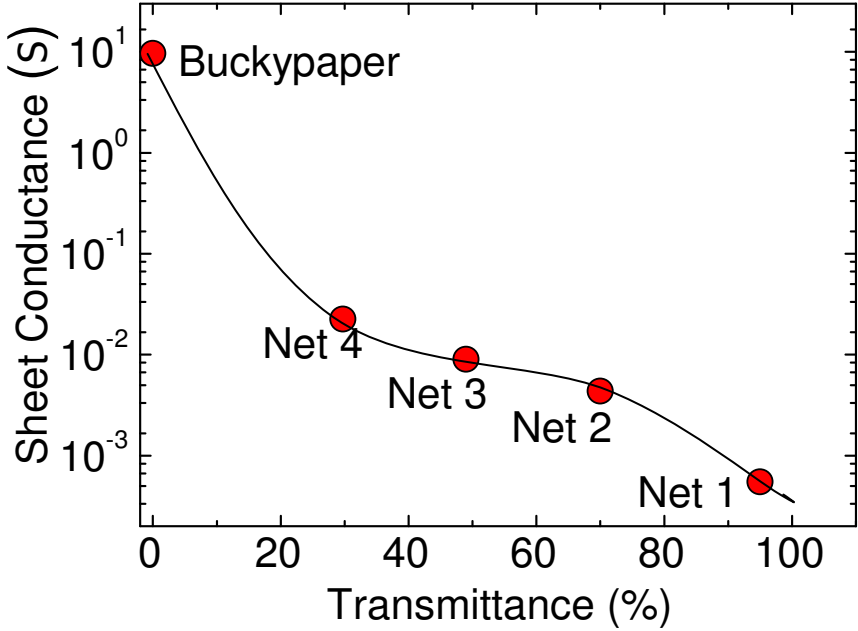
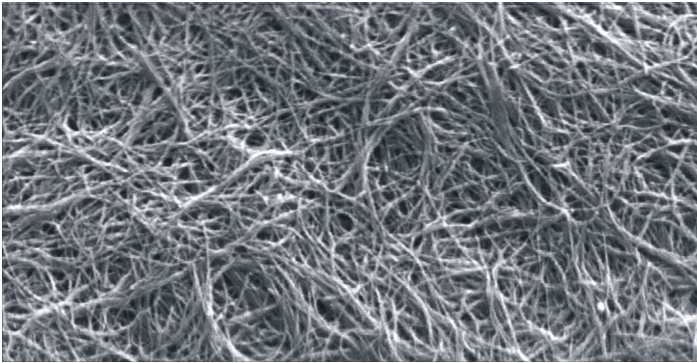
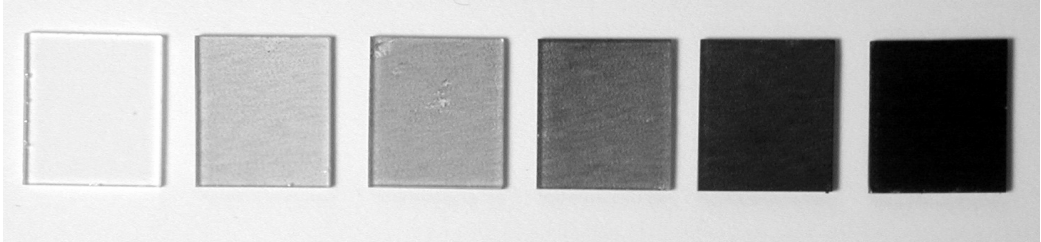
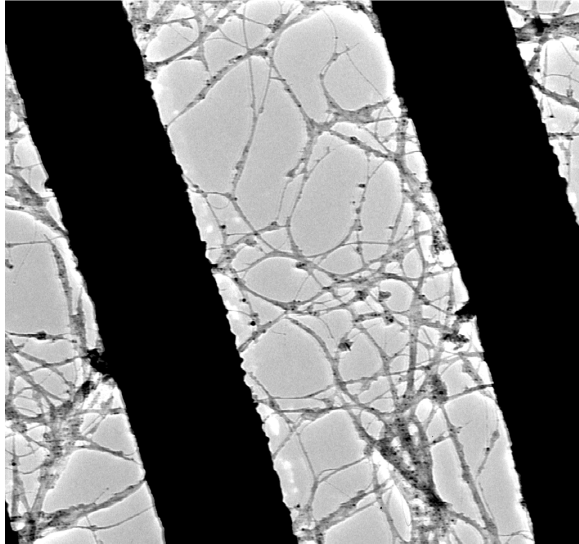
Electron transport in individual SWNT



I-V plots before and after Ar⁺-irradiation (5.10¹¹ ion/cm²):

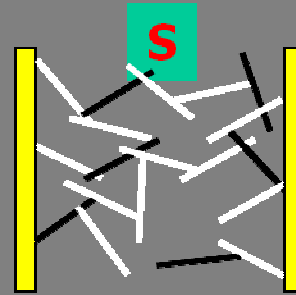


SWNT networks

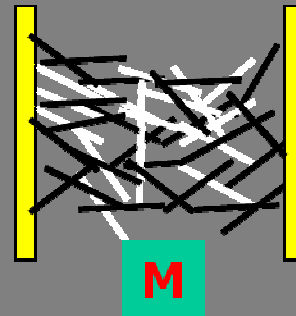


Electronic properties of SWNT networks

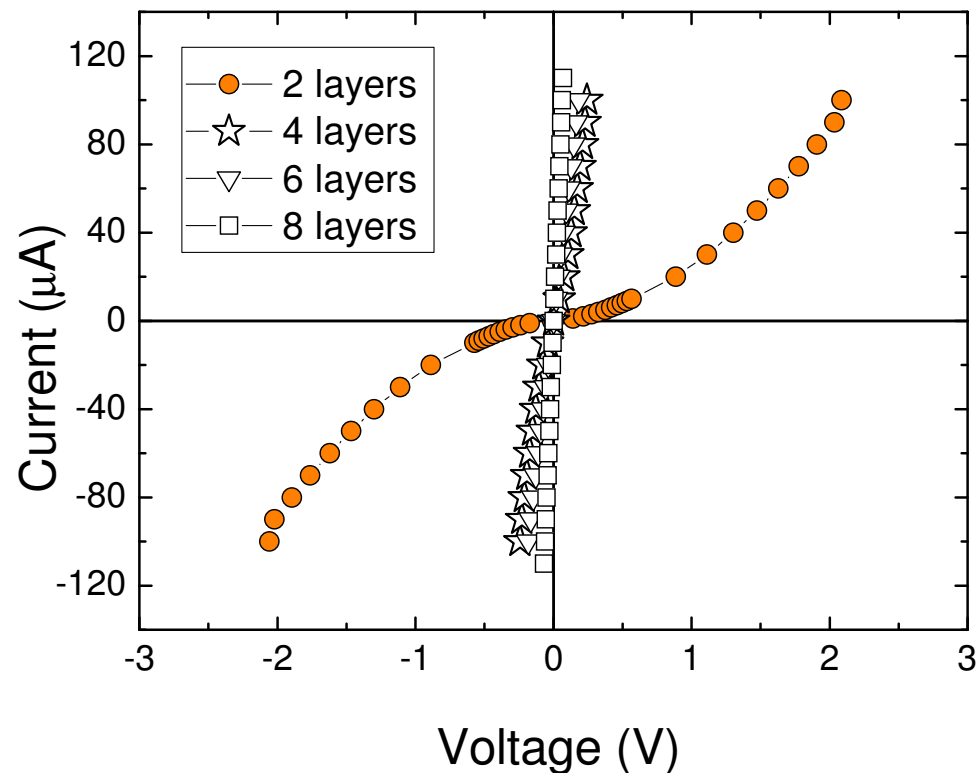
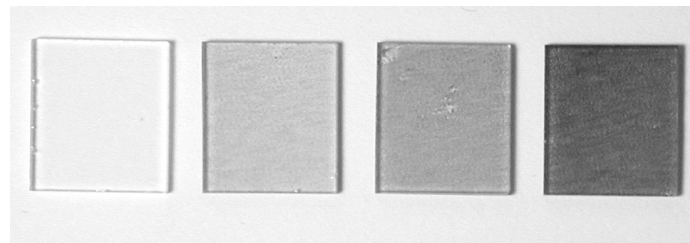
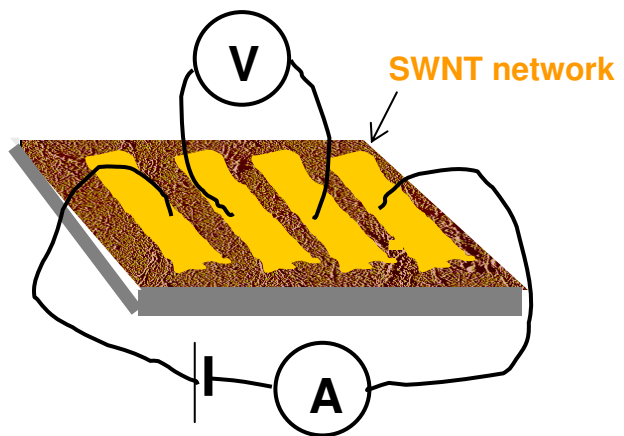
1. Thin SWNT network: semiconducting



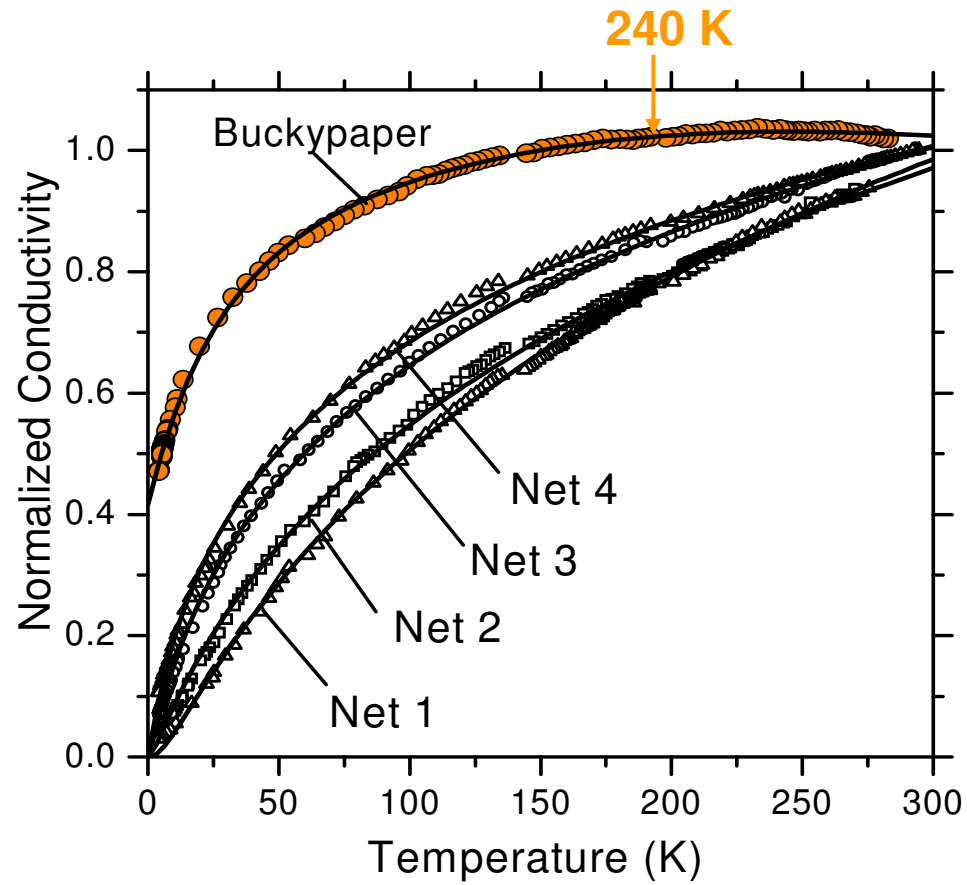
2. Thick SWNT networks: metallic



Thickness: current vs. bias voltage

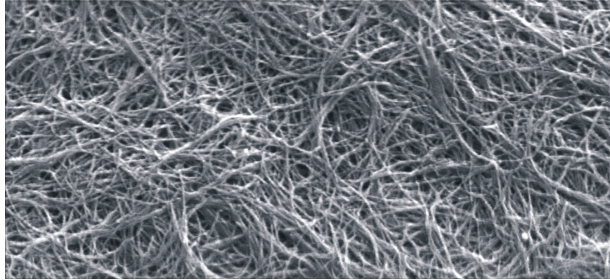


Thickness: Temperature dependences of conductivity $G(T)$



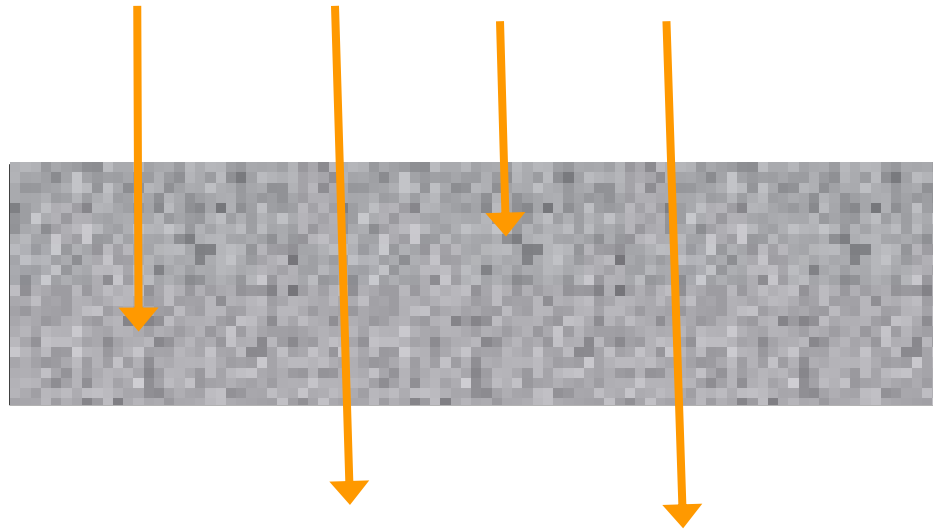
V. Skákalová, A. B. Kaiser, Y.-S. Woo, and S. Roth, PHYSICAL REVIEW B 74, 085403 (2006)

Effect of irradiation by 23 MeV C⁴⁺ ions

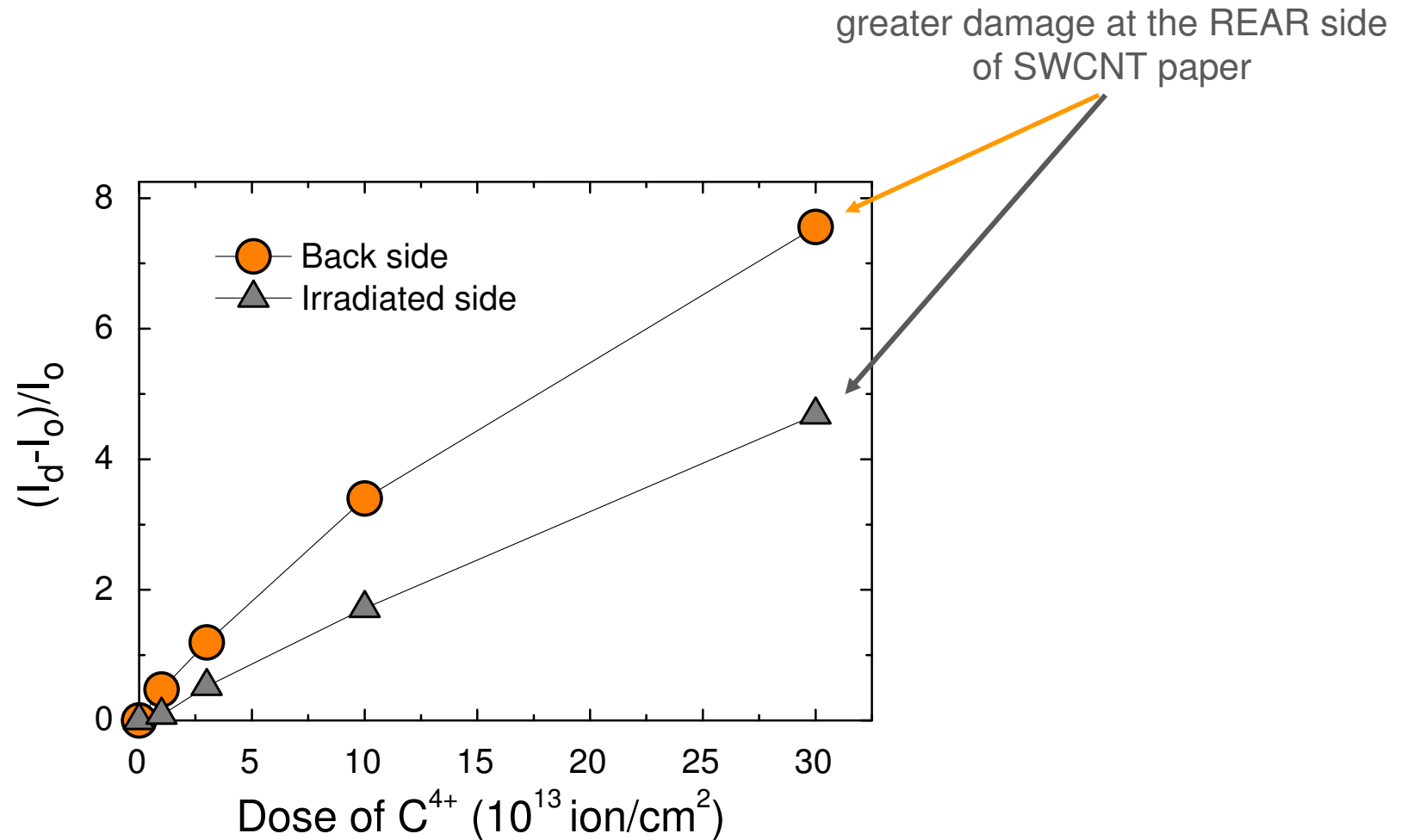


Penetration depth > Thickness 40 μm

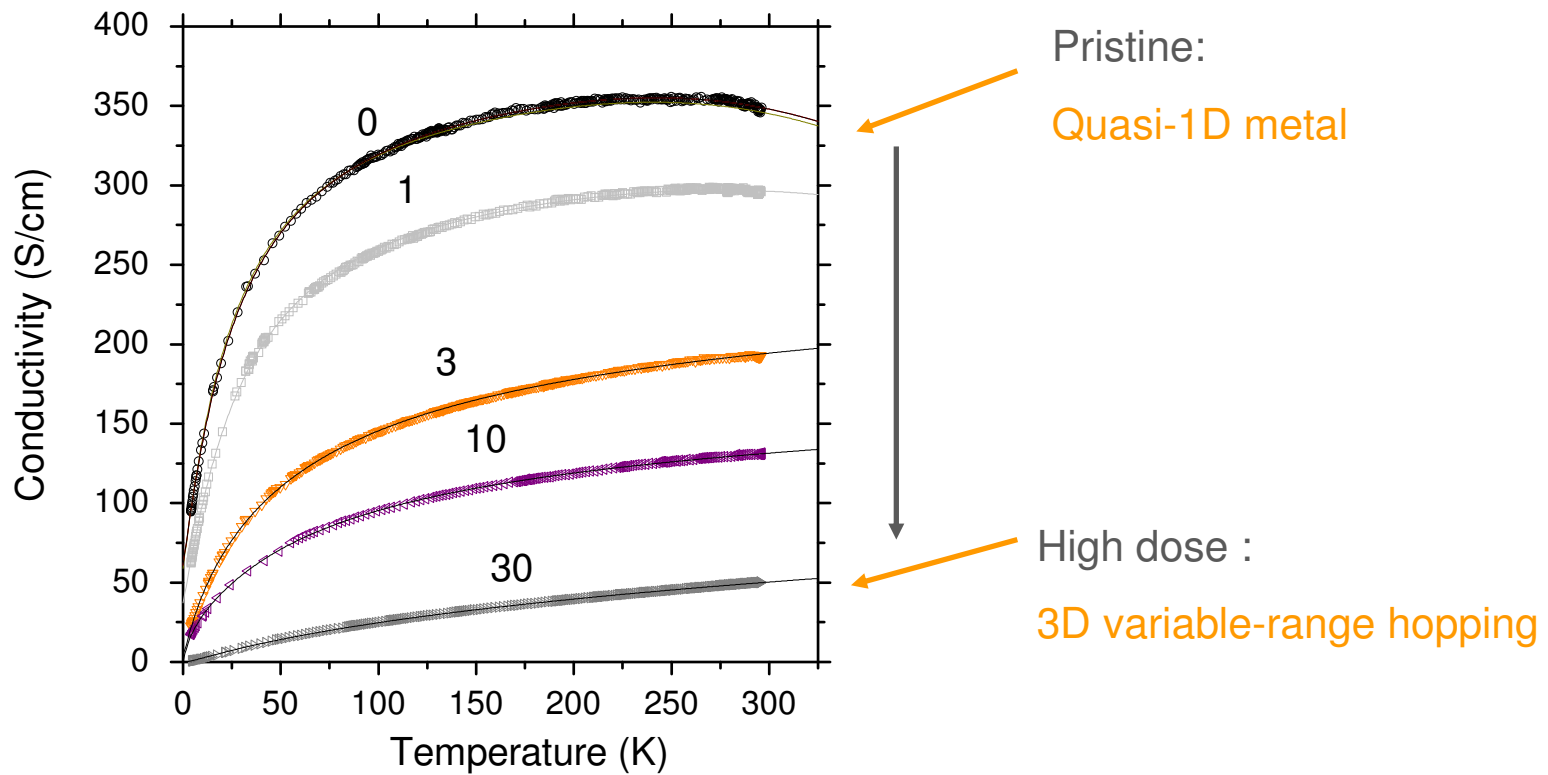
ions



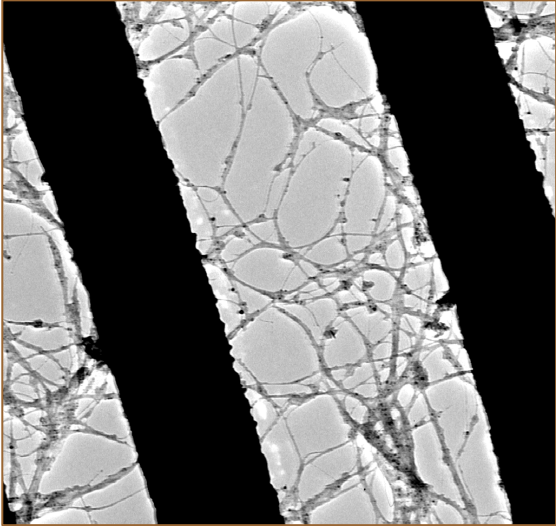
$\Delta I/I$ of the D-mode vs. Dose of C^{4+} ions



C^{4+} -irradiation of SWNT paper: T-dependent conductivity

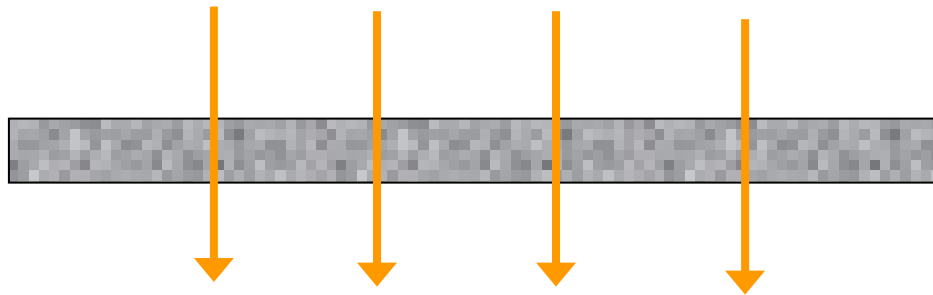


Thin SWNT networks irradiated by 30 keV Ar⁺ ions

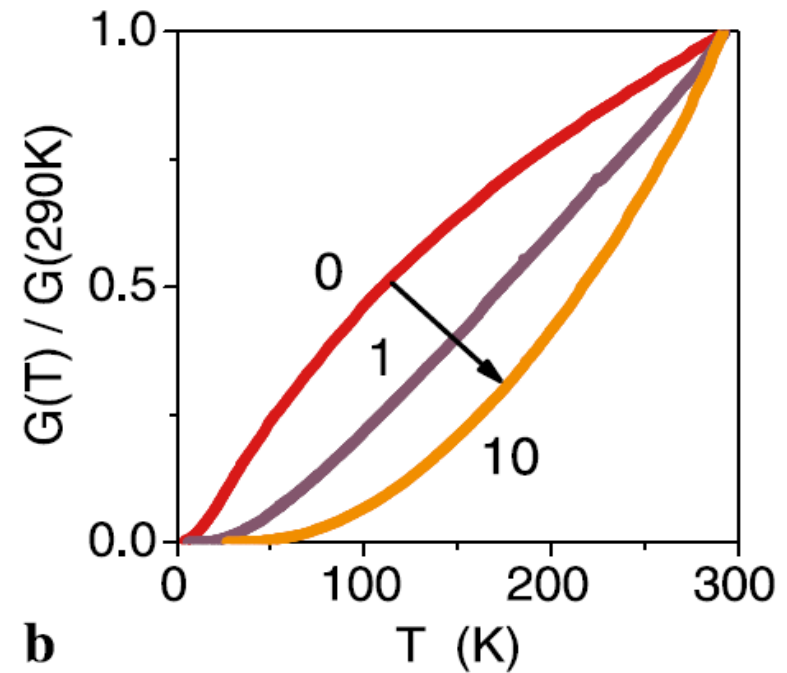
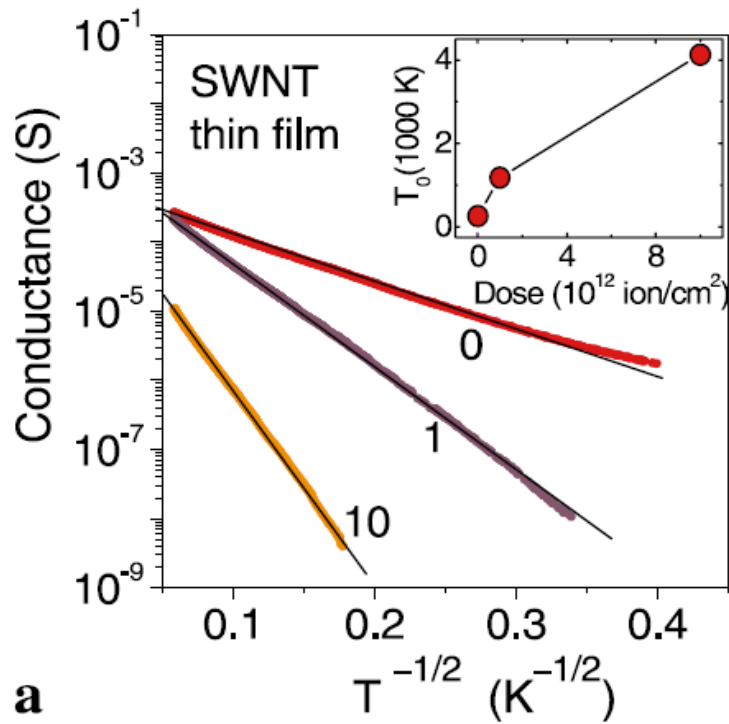


Penetration depth < Thickness 100 nm

ions



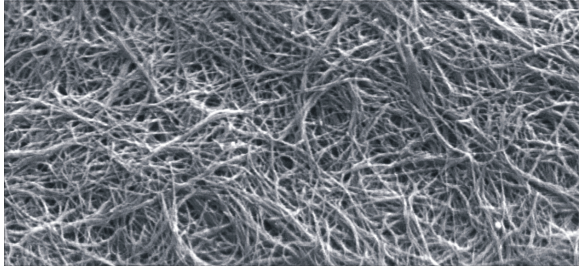
Electrical conductance of Ar⁺ irradiated thin SWNT networks



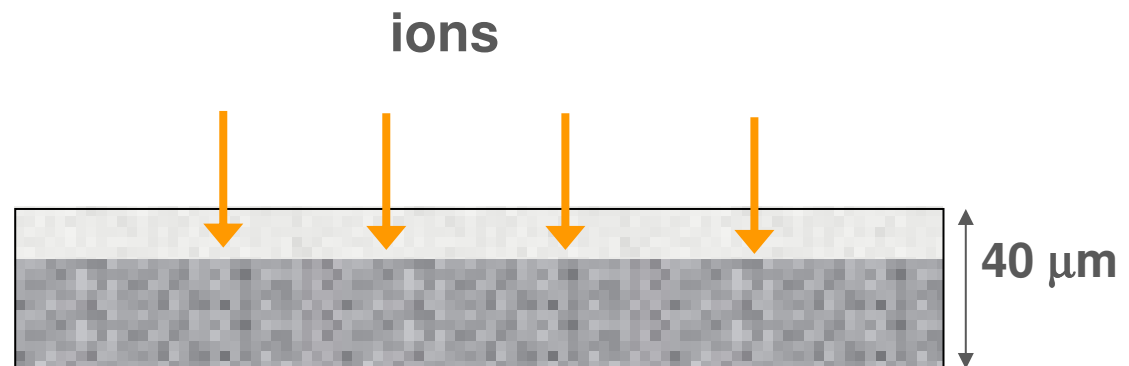
Variable-Range Hopping:

$$\sigma(T) = \sigma_0 \exp \left[- \left(\frac{T_0}{T} \right)^{1/(1+d)} \right]$$

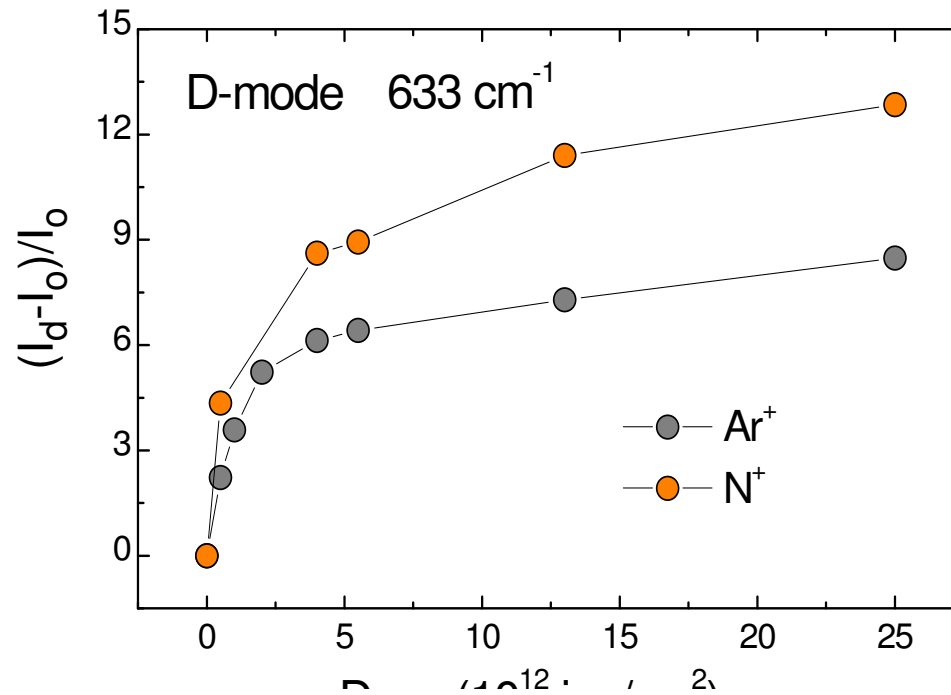
Thick SWNT networks irradiated by 30 keV Ar⁺ ions



Penetration depth < Thickness 40 μm



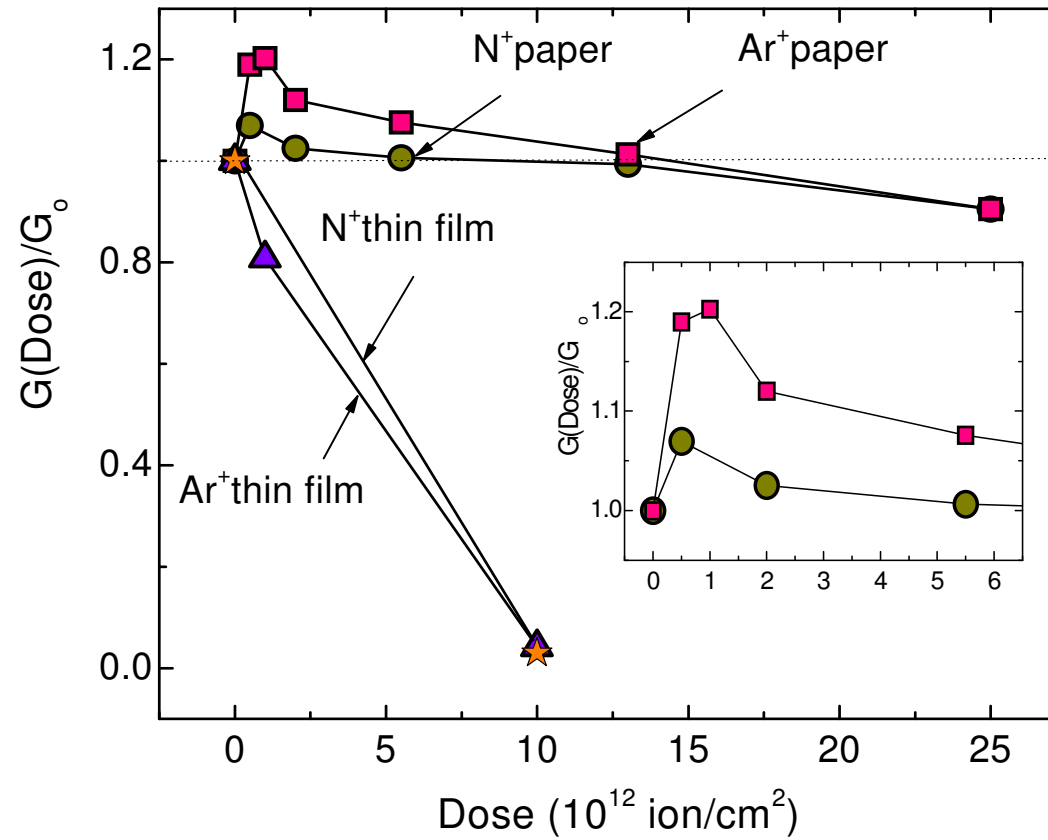
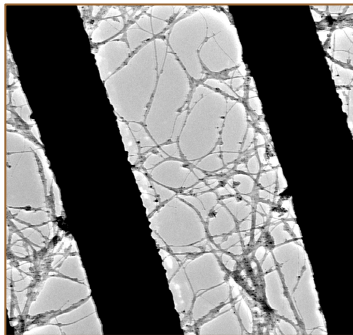
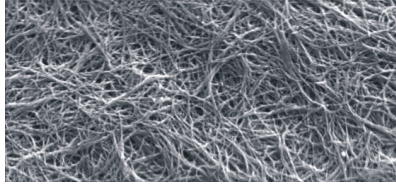
Raman spectra of irradiated thick SWNT papers by 30 keV ions



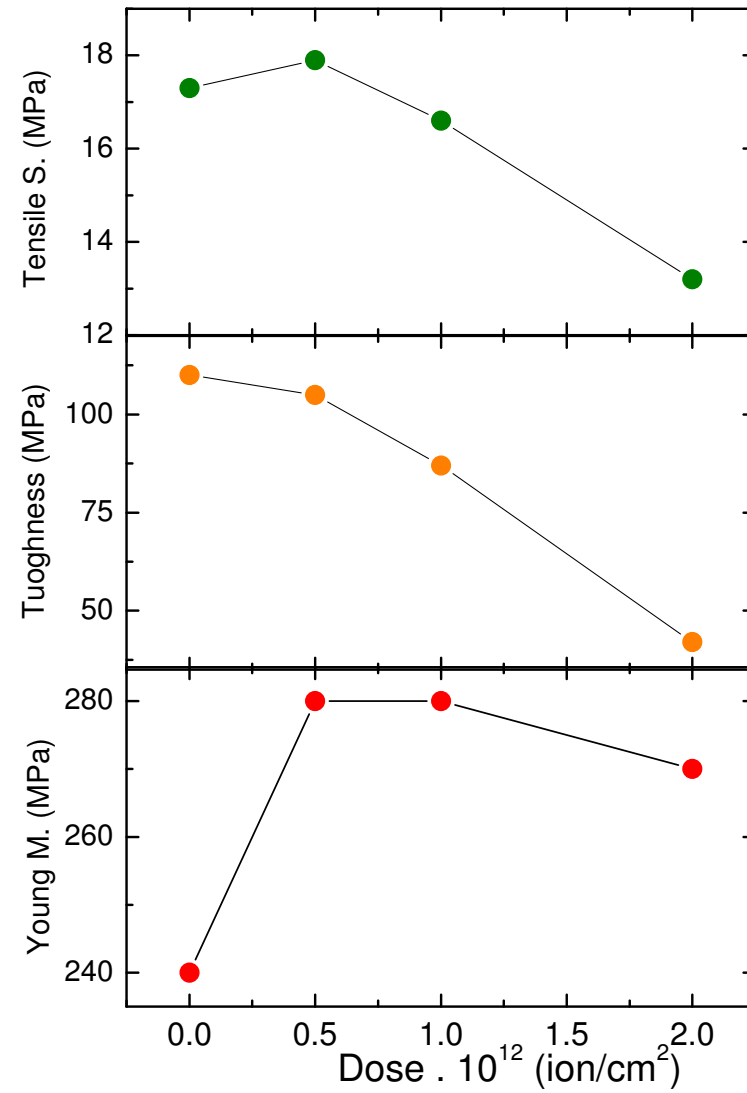
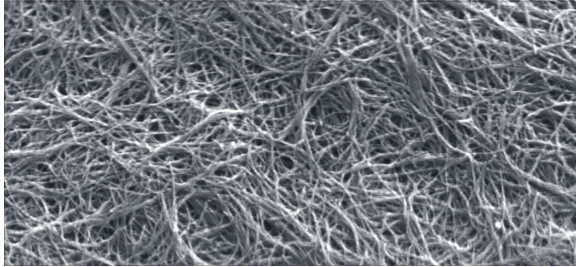
Penetration depth of the laser beam $\sim 1\mu\text{m}$ > Penetration depth of the ions

Penetration depth of the Ar^+ ions < Penetration depth of the N^+ ions

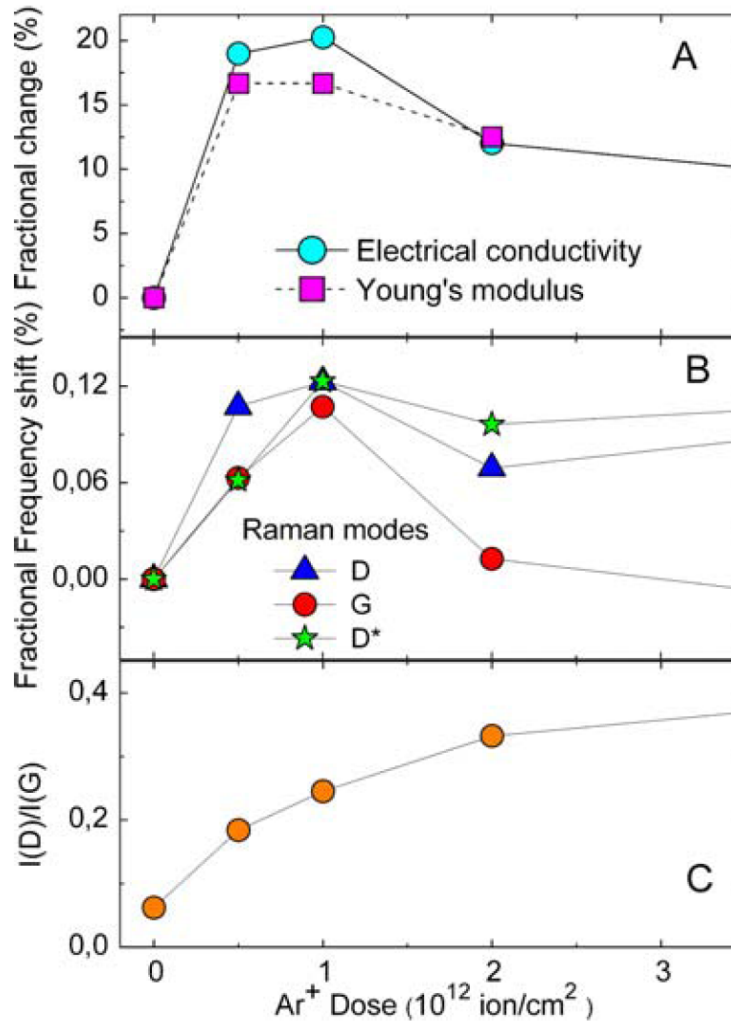
Electrical conductance of irradiated thick SWNT papers



Mechanical properties of irradiated thick SWNT papers



Correlation between Conductivity, Young's modulus and Raman mode shifts changes in modified carbon nanotube networks



Summary

Raman spectra:

- D-mode increases and saturate with the increasing dose
- The new (forbidden) IFM modes as a consequence of broken symmetry

2. Optical spectra:

- The absorption peaks of Van Hove singularities decrease

3. Electrical conductivity:

- If the thickness of layers is smaller than the penetration depth of ions, the conductivity decreases with the dose of irradiation
- A maximum in the conductivity is observed at low ion energies. This is explained by thermal annealing of the sample.

The strong correlation between Conductivity, Young modulus and Raman frequencies shift showing a maximum